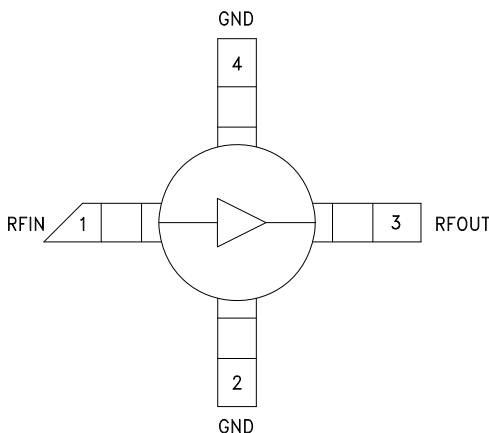


### Typical Applications

The HMC474MP86 & HMC474MP86E is an ideal RF/IF gain block for:

- Cellular / PCS / 3G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment

### Functional Diagram



### Features

- Gain: 15.5 dB
- P1dB Output Power: +8 dBm
- Output IP3: +22 dBm
- Cascadable 50 Ohm I/Os
- Single Supply: +3V to +10V
- Included in the HMC-DK001 Designer's Kit

### General Description

The HMC474MP86 & HMC474MP86E are general purpose SiGe Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifiers covering DC to 6 GHz. This Micro-P packaged amplifier can be used as a cascadable 50 Ohm RF/IF gain stage with up to +10 dBm output power. The HMC474MP86(E) offer 15.5 dB of gain with a +22 dBm output IP3 at 850 MHz while requiring only 25 mA from a single positive supply. The Darlington feedback pair used results in reduced sensitivity to normal process variations and excellent gain stability over temperature while requiring a minimal number of external bias components.

### Electrical Specifications, $V_s = 5V$ , $R_{bias} = 110 \text{ Ohm}$ , $T_A = +25^\circ \text{ C}$

Parameter		Min.	Typ.	Max.	Units
Gain	DC - 1.0 GHz	13	15.5		dB
	1.0 - 2.0 GHz	12	14		dB
	2.0 - 3.0 GHz	10	12		dB
	3.0 - 4.0 GHz	9	11		dB
	4.0 - 5.0 GHz	8	10		dB
	5.0 - 6.0 GHz	7	9		dB
Gain Variation Over Temperature	DC - 6 GHz		0.01	0.015	dB/ °C
Input Return Loss	DC - 1.0 GHz		15		dB
	1.0 - 4.0 GHz		16		dB
	4.0 - 5.0 GHz		19		dB
	5.0 - 6.0 GHz		16		dB
Output Return Loss	DC - 5 GHz		17		dB
	5.0 - 6.0 GHz		13		dB
Reverse Isolation	DC - 4 GHz		17		dB
Output Power for 1 dB Compression (P1dB)	0.5 - 4.0 GHz	5	8		dBm
	4.0 - 5.0 GHz	4	7		dBm
	5.0 - 6.0 GHz	3	6		dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)	0.5 - 4.0 GHz		22		dBm
	4.0 - 5.0 GHz		20		dBm
	5.0 - 6.0 GHz		17		dBm
Noise Figure	DC - 5 GHz		3		dB
	5.0 - 6.0 GHz		3.4		dB
Supply Current (Icq)			25		mA

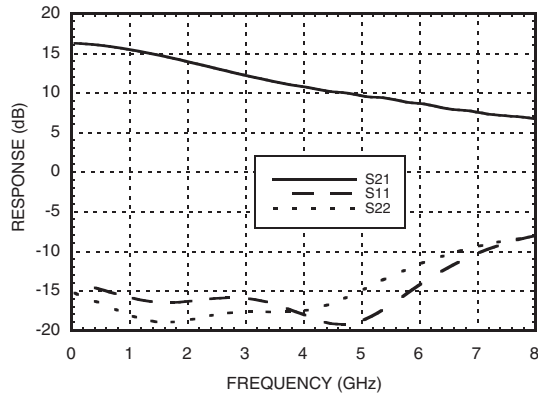
Note: Data taken with broadband bias tee on device output.

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:  
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373

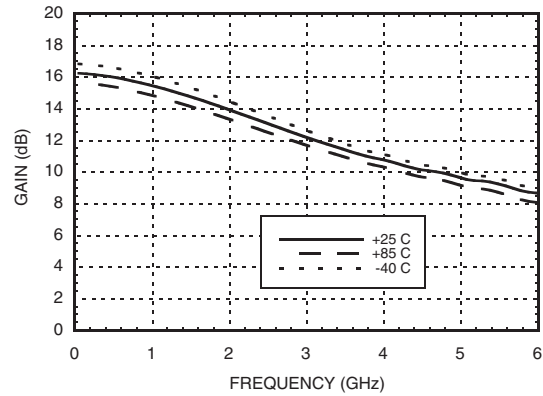
Order On-Line at [www.hittite.com](http://www.hittite.com)  
[www.BDTIC.com/Hittite/](http://www.BDTIC.com/Hittite/)



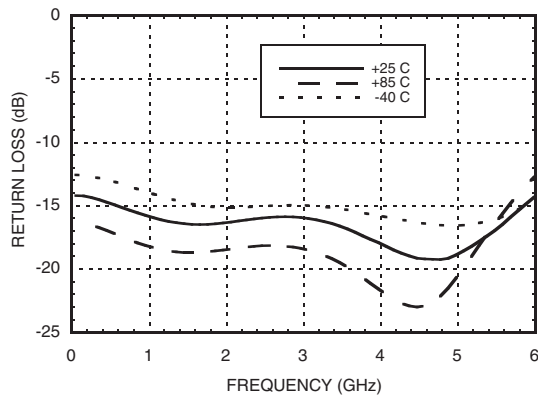
**Broadband Gain & Return Loss**



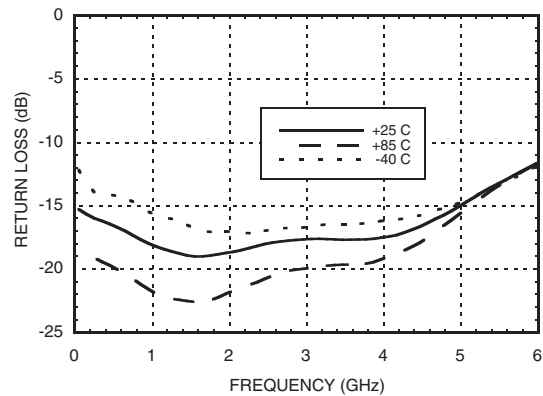
**Gain vs. Temperature**



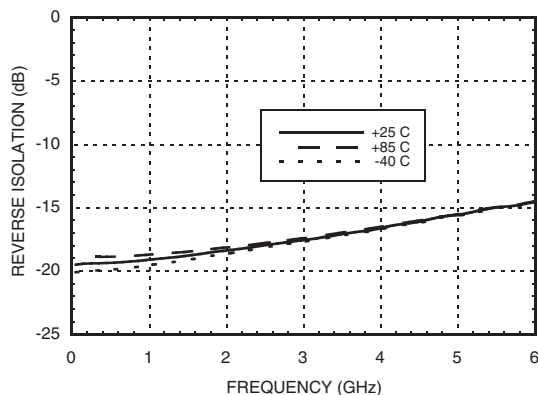
**Input Return Loss vs. Temperature**



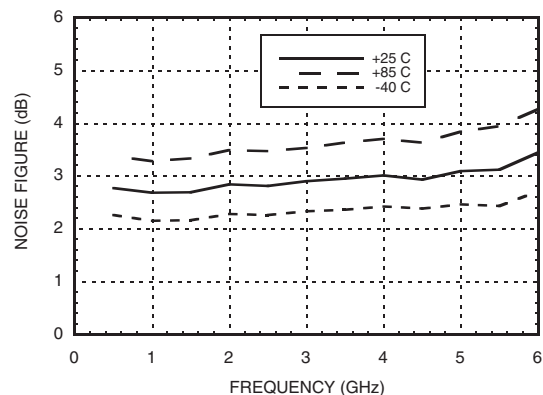
**Output Return Loss vs. Temperature**



**Reverse Isolation vs. Temperature**



**Noise Figure vs. Temperature**





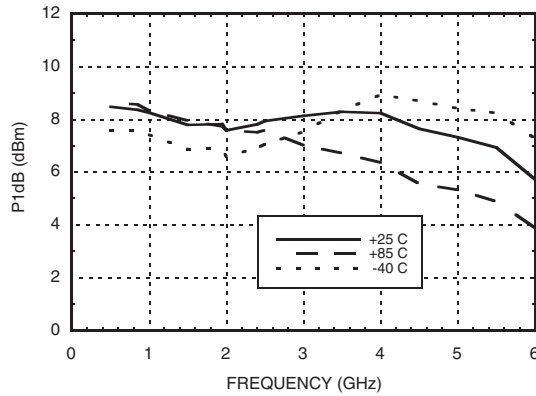
# HMC474MP86 / 474MP86E

## SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 6 GHz

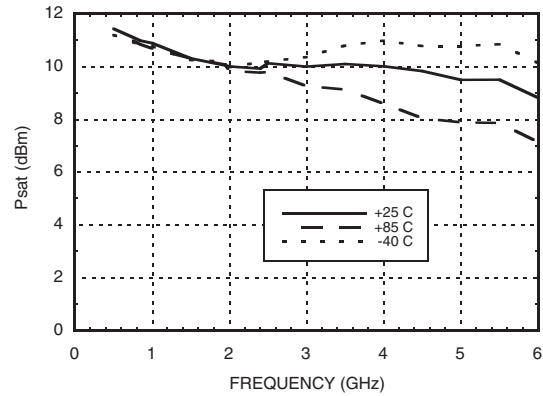
9

DRIVER & GAIN BLOCK AMPLIFIERS - SMT

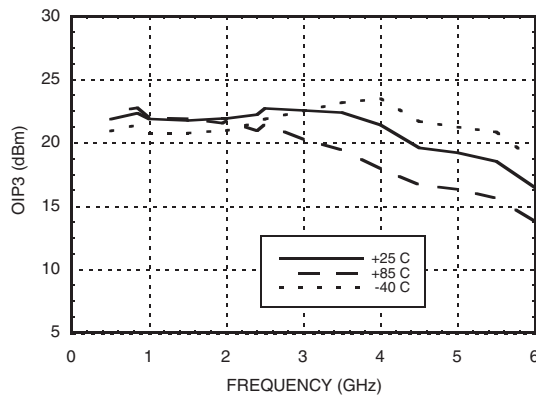
**P1dB vs. Temperature**



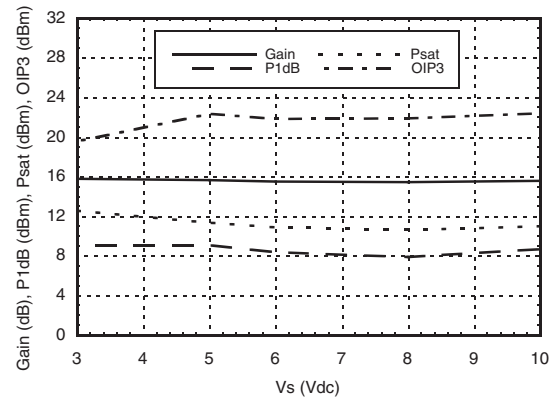
**Psat vs. Temperature**



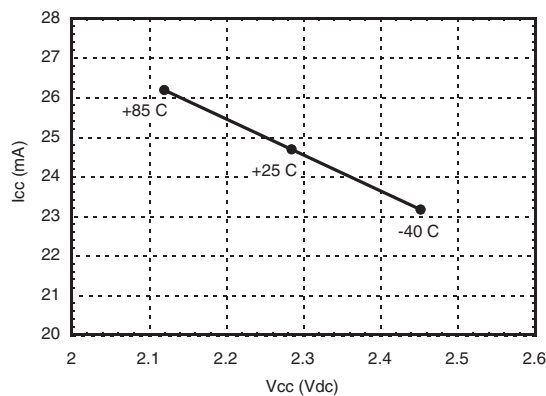
**Output IP3 vs. Temperature**



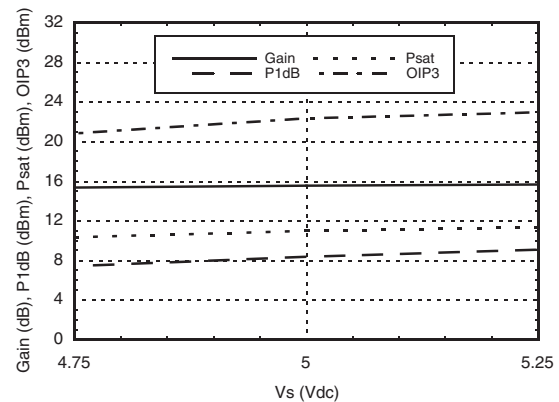
**Gain, Power & OIP3 vs. Supply Voltage for Constant Icc= 25 mA @ 850 MHz**



**Icc vs. Vcc Over Temperature for Fixed Vs= 5V, RBIAS= 110 Ohms**



**Gain, Power & OIP3 vs. Supply Voltage for Rs = 110 Ohms @ 850 MHz**



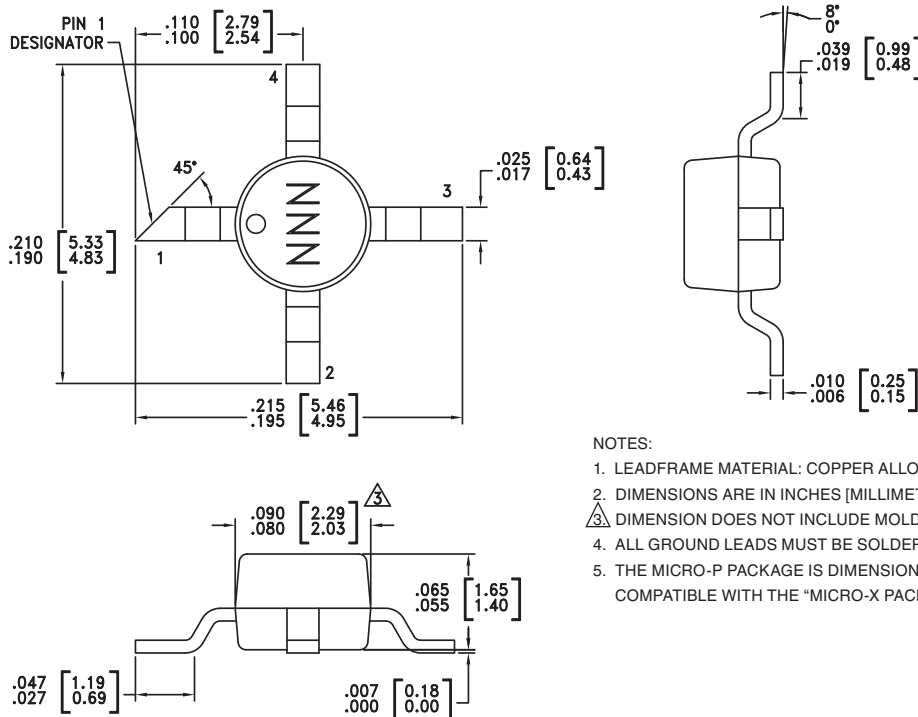
### Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+6.0 Vdc
Collector Bias Current (Icc)	35 mA
RF Input Power (RFIN)(Vcc = +2.4 Vdc)	+5 dBm
Junction Temperature	150 °C
Continuous P <sub>diss</sub> (T = 85 °C) (derate 4.3 mW/°C above 85 °C)	0.280 W
Thermal Resistance (junction to lead)	232 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1B



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
5. THE MICRO-P PACKAGE IS DIMENSIONALLY COMPATIBLE WITH THE "MICRO-X PACKAGE"

### Package Information

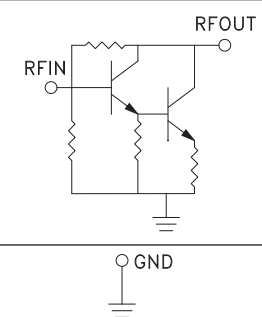
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking
HMC474MP86	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	474
HMC474MP86E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	474

[1] Max peak reflow temperature of 235 °C

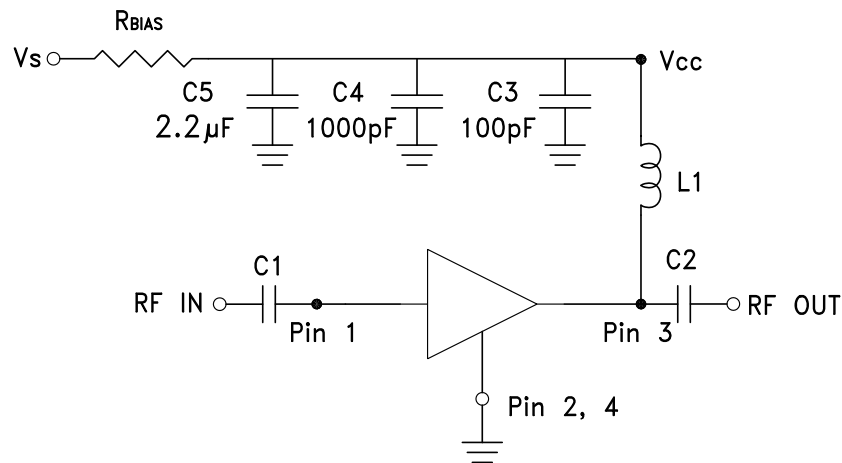
[2] Max peak reflow temperature of 260 °C

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20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373

### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. An off chip DC blocking capacitor is required.	
3	RFOUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins must be connected to RF/DC ground.	

### Application Circuit



### Recommended Bias Resistor Values for $I_{CC} = 25 \text{ mA}$ , $R_{BIAS} = (V_s - V_{CC}) / I_{CC}$

Supply Voltage ( $V_s$ )	3V	5V	6V	8V	10V
$R_{BIAS}$ VALUE	30 $\Omega$	110 $\Omega$	150 $\Omega$	240 $\Omega$	300 $\Omega$
$R_{BIAS}$ POWER RATING	1/8 W	1/8 W	1/4 W	1/2 W	1/2 W

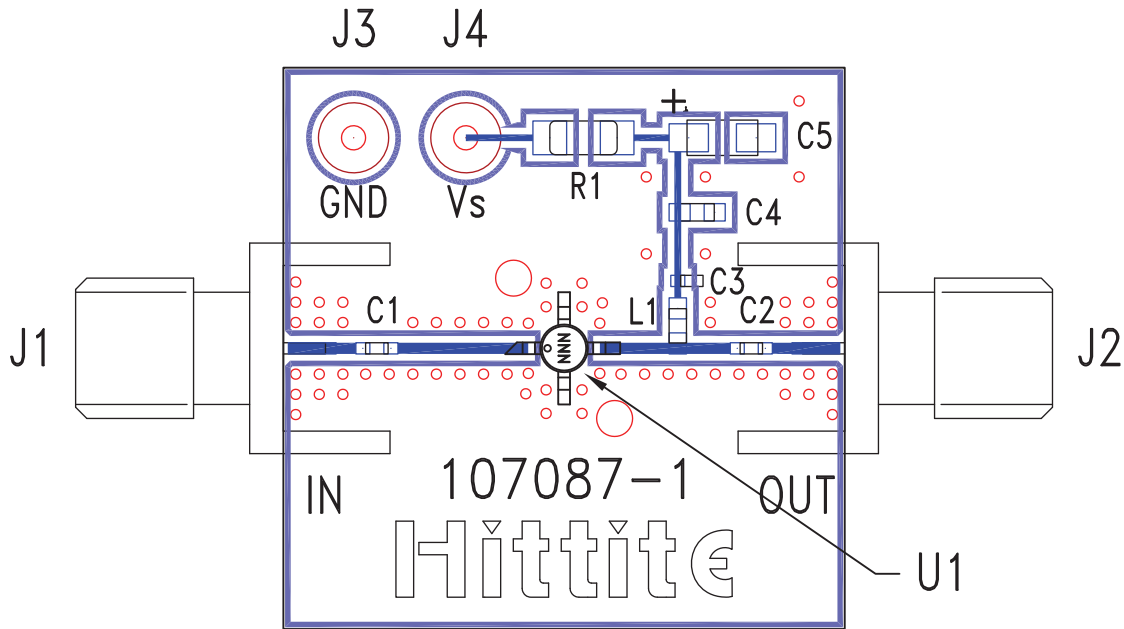
**Note:**

- External blocking capacitors are required on RFIN and RFOUT.
- $R_{BIAS}$  provides DC bias stability over temperature.

### Recommended Component Values for Key Application Frequencies

Component	Frequency (MHz)							
	50	900	1900	2200	2400	3500	5200	5500
L1	270 nH	56 nH	18 nH	18 nH	15 nH	8.2 nH	6.8 nH	3.3 nH
C1, C2	0.01 $\mu F$	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF

**Evaluation PCB**



**List of Materials for Evaluation PCB 107179 [1]**

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	DC Pin
C1, C2	Capacitor, 0402 Pkg.
C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0603 Pkg.
C5	2.2 $\mu$ F Capacitor, Tantalum
R1	Resistor, 1210 Pkg.
L1	Inductor, 0603 Pkg.
U1	HMC474MP86 / HMC474MP86E
PCB [2]	107087 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.